



# PUMH9

50 V, 100 mA NPN/NPN resistor-equipped double transistor;  
R1 = 10 k $\Omega$ , R2 = 47 k $\Omega$

1 July 2022

Product data sheet

## 1. General description

NPN/NPN Resistor-Equipped double Transistor (RET) in a very small SOT363 (SC-88) Surface-Mounted Device (SMD) plastic package.

PNP/PNP complement: PUMB9

NPN/PNP complement: PUMD9

## 2. Features and benefits

- 100 mA output current capability
- Built-in bias resistors
- Simplifies circuit design
- Reduces component count
- Reduces pick and place costs

## 3. Applications

- Digital application in automotive and industrial segments
- Cost-saving alternative for BC847 series in digital applications
- Controlling IC inputs
- Switching loads

## 4. Quick reference data

Table 1. Quick reference data

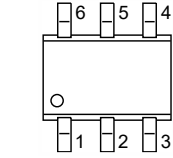
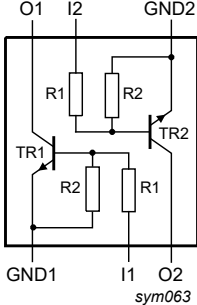
| Symbol                | Parameter                 | Conditions | Min | Typ | Max | Unit |            |
|-----------------------|---------------------------|------------|-----|-----|-----|------|------------|
| <b>Per transistor</b> |                           |            |     |     |     |      |            |
| V <sub>CEO</sub>      | collector-emitter voltage | open base  | -   | -   | 50  | V    |            |
| I <sub>O</sub>        | output current            |            | -   | -   | 100 | mA   |            |
| R1                    | bias resistor 1 (input)   |            | [1] | 7   | 10  | 13   | k $\Omega$ |
| R2/R1                 | bias resistor ratio       |            | [1] | 3.7 | 4.7 | 5.7  |            |

[1] See "Section 11: Test information" for resistor calculation and test conditions.

50 V, 100 mA NPN/NPN resistor-equipped double transistor; R1 = 10 kΩ, R2 = 47 kΩ

## 5. Pinning information

Table 2. Pinning information

| Pin | Symbol | Description            | Simplified outline  | Graphic symbol   |
|-----|--------|------------------------|---|--|
| 1   | GND1   | GND (emitter) TR1      |  <p><b>TSSOP6 (SOT363)</b></p> |  <p style="text-align: center;"><i>sym063</i></p> |
| 2   | I1     | input (base) TR1       |   |  |
| 3   | O2     | output (collector) TR2 |   |  |
| 4   | GND2   | GND (emitter) TR2      |   |  |
| 5   | I2     | input (base) TR2       |   |  |
| 6   | O1     | output (collector) TR1 |   |  |

## 6. Ordering information

Table 3. Ordering information

| Type number | Package |   |         |
|-------------|---------|---|---------|
|             | Name    | Description   | Version |
| PUMH9       | TSSOP6  | plastic, surface-mounted package; 6 leads; 0.65 mm pitch; 2.1 mm x 1.25 mm x 0.95 mm body | SOT363  |

## 7. Marking

Table 4. Marking codes

| Type number | Marking code <sup>[1]</sup> |
|-------------|-----------------------------|
| PUMH9       | H%9                         |

[1] % = placeholder for manufacturing site code

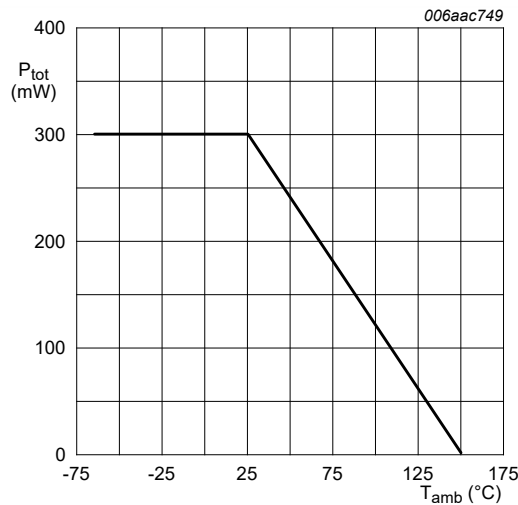
## 8. Limiting values

**Table 5. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol                | Parameter                 | Conditions                  |     | Min | Max | Unit |
|-----------------------|---------------------------|-----------------------------|-----|-----|-----|------|
| <b>Per transistor</b> |                           |                             |     |     |     |      |
| $V_{CBO}$             | collector-base voltage    | open emitter                |     | -   | 50  | V    |
| $V_{CEO}$             | collector-emitter voltage | open base                   |     | -   | 50  | V    |
| $V_{EBO}$             | emitter-base voltage      | open collector              |     | -   | 6   | V    |
| $V_I$                 | input voltage             | positive                    |     | -   | 40  | V    |
|                       |                           | negative                    |     | -   | -6  | V    |
| $I_O$                 | output current            |                             |     | -   | 100 | mA   |
| $P_{tot}$             | total power dissipation   | $T_{amb} \leq 25\text{ °C}$ | [1] | -   | 200 | mW   |
| <b>Per device</b>     |                           |                             |     |     |     |      |
| $P_{tot}$             | total power dissipation   | $T_{amb} \leq 25\text{ °C}$ | [1] | -   | 300 | mW   |
| $T_j$                 | junction temperature      |                             |     | -   | 150 | °C   |
| $T_{amb}$             | ambient temperature       |                             |     | -55 | 150 | °C   |
| $T_{stg}$             | storage temperature       |                             |     | -65 | 150 | °C   |

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided, 35 μm copper, tin-plated and standard footprint.



FR4 PCB, single-sided, 35 μm copper, tin-plated and standard footprint

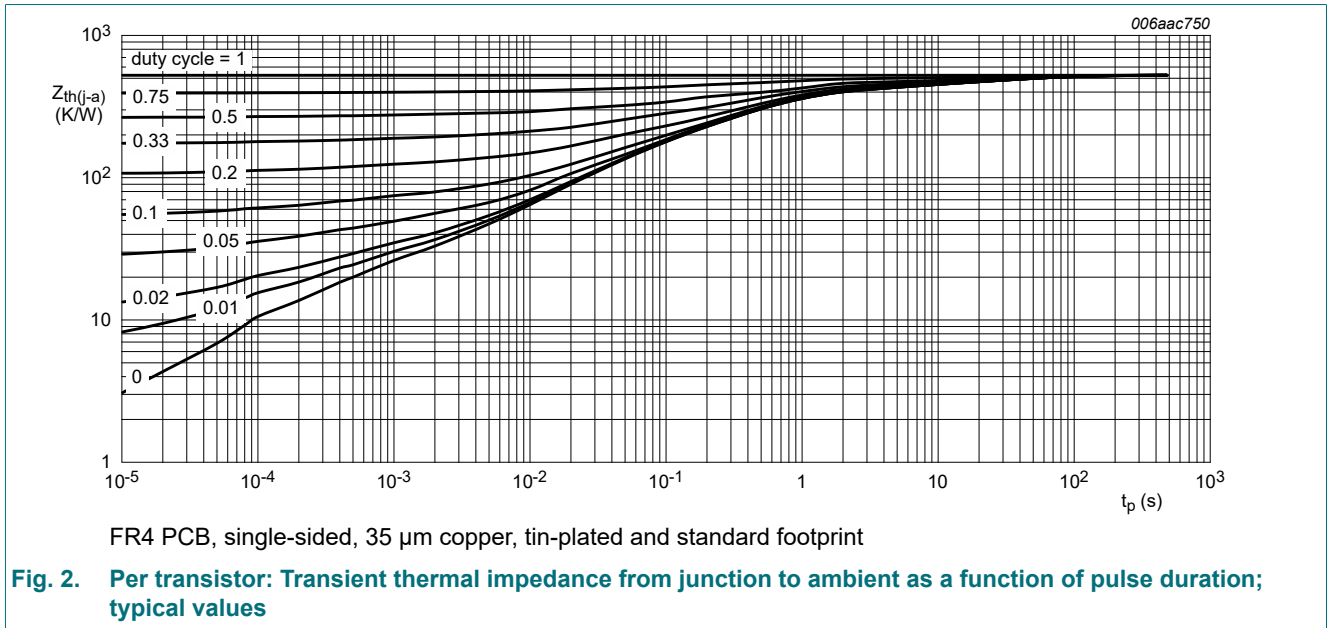
**Fig. 1. Per device: Power derating curve**

## 9. Thermal characteristics

Table 6. Thermal characteristics

| Symbol                | Parameter                                   | Conditions  | Min | Typ | Max | Unit |
|-----------------------|---|-------------|-----|-----|-----|------|
| <b>Per transistor</b> |   |             |     |     |     |      |
| $R_{th(j-a)}$         | thermal resistance from junction to ambient | in free air | [1] | -   | 625 | K/W  |
| <b>Per device</b>     |   |             |     |     |     |      |
| $R_{th(j-a)}$         | thermal resistance from junction to ambient | in free air | [1] | -   | 417 | K/W  |

[1] Device mounted on an FR4 PCB, single-sided, 35 μm copper, tin-plated and standard footprint.



## 10. Characteristics

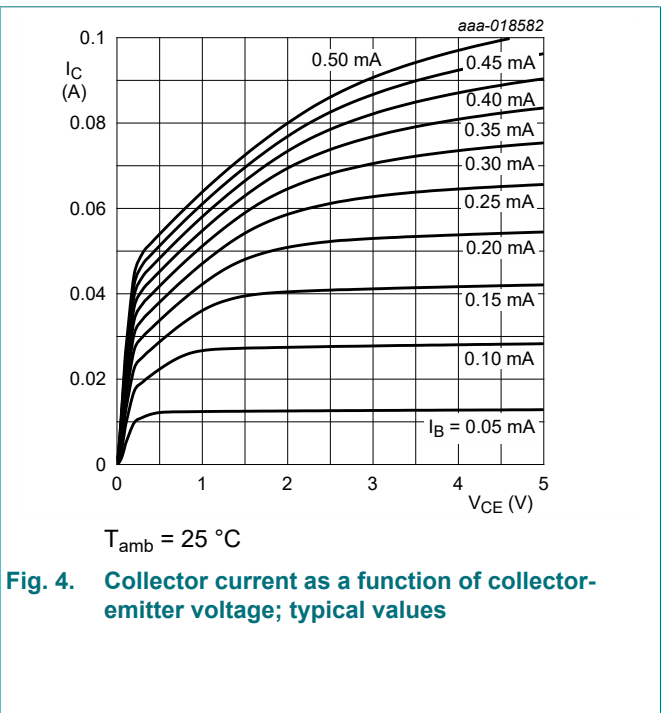
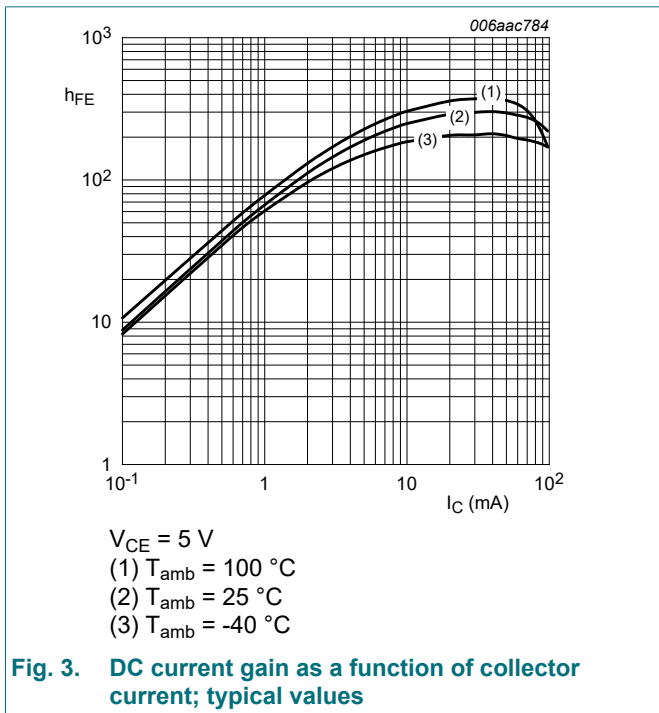
**Table 7. Characteristics**

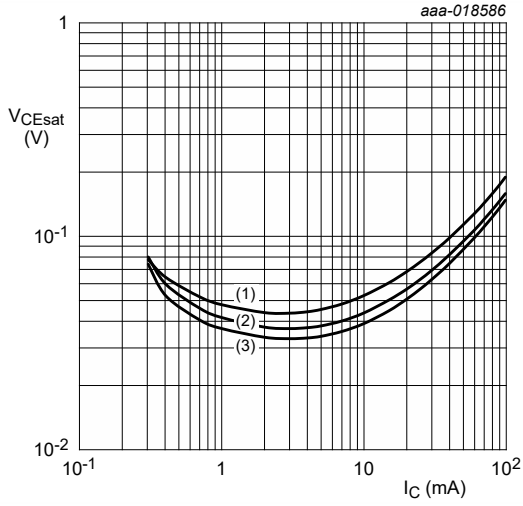
$T_{amb} = 25\text{ °C}$  unless otherwise specified.

| Symbol                | Parameter                            | Conditions   | Min | Typ | Max | Unit          |     |
|-----------------------|--------------------------------------|--|-----|-----|-----|---------------|-----|
| <b>Per transistor</b> |                                      |  |     |     |     |               |     |
| $V_{(BR)CBO}$         | collector-base breakdown voltage     | $I_C = 100\text{ }\mu\text{A}; I_E = 0\text{ A}$                             | 50  | -   | -   | V             |     |
| $V_{(BR)CEO}$         | collector-emitter breakdown voltage  | $I_C = 2\text{ mA}; I_B = 0\text{ A}$  | 50  | -   | -   | V             |     |
| $I_{CBO}$             | collector-base cut-off current       | $V_{CB} = 50\text{ V}; I_E = 0\text{ A}$                                     | -   | -   | 100 | nA            |     |
| $I_{CEO}$             | collector-emitter cut-off current    | $V_{CE} = 30\text{ V}; I_B = 0\text{ A}$                                     | -   | -   | 100 | nA            |     |
|                       |                                      | $V_{CE} = 30\text{ V}; I_B = 0\text{ A}; T_j = 150\text{ °C}$                | -   | -   | 5   | $\mu\text{A}$ |     |
| $I_{EBO}$             | emitter-base cut-off current         | $V_{EB} = 5\text{ V}; I_C = 0\text{ A}$                                      | -   | -   | 150 | $\mu\text{A}$ |     |
| $h_{FE}$              | DC current gain                      | $V_{CE} = 5\text{ V}; I_C = 5\text{ mA}$                                     | 100 | -   | -   |               |     |
| $V_{CEsat}$           | collector-emitter saturation voltage | $I_C = 5\text{ mA}; I_B = 0.25\text{ mA}$                                    | -   | -   | 100 | mV            |     |
| $V_{I(off)}$          | off-state input voltage              | $V_{CE} = 5\text{ V}; I_C = 100\text{ }\mu\text{A}$                          | -   | 0.7 | 0.5 | V             |     |
| $V_{I(on)}$           | on-state input voltage               | $V_{CE} = 0.3\text{ V}; I_C = 1\text{ mA}$                                   | 1.4 | 0.8 | -   | V             |     |
| R1                    | bias resistor 1 (input)              |  | [1] | 7   | 10  | 13            | kΩ  |
| R2/R1                 | bias resistor ratio                  |  | [1] | 3.7 | 4.7 | 5.7           |     |
| $C_c$                 | collector capacitance                | $V_{CB} = 10\text{ V}; I_E = 0\text{ A}; i_e = 0\text{ A}; f = 1\text{ MHz}$ | -   | -   | 2.5 | pF            |     |
| $f_T$                 | transition frequency                 | $V_{CE} = 5\text{ V}; I_C = 10\text{ mA}; f = 100\text{ MHz}$                | [2] | -   | 230 | -             | MHz |

[1] See "Section 11: Test information" for resistor calculation and test conditions.

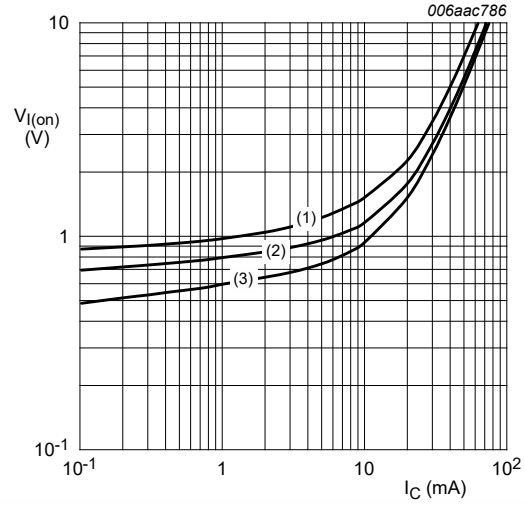
[2] Characteristics of built-in transistor





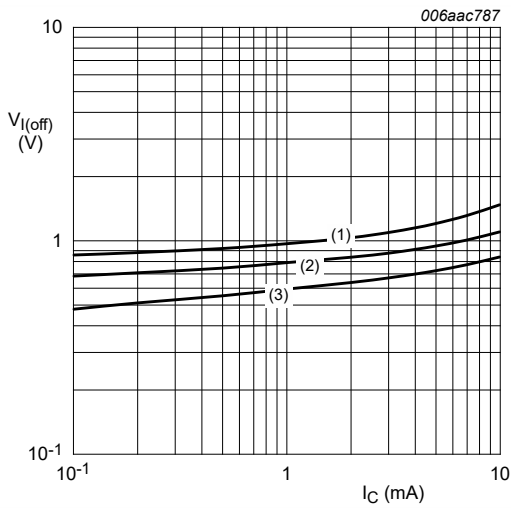
$I_C/I_B = 20$   
 (1)  $T_{amb} = 100\text{ }^\circ\text{C}$   
 (2)  $T_{amb} = 25\text{ }^\circ\text{C}$   
 (3)  $T_{amb} = -40\text{ }^\circ\text{C}$

**Fig. 5. Collector-emitter saturation voltage as a function of collector current; typical values**



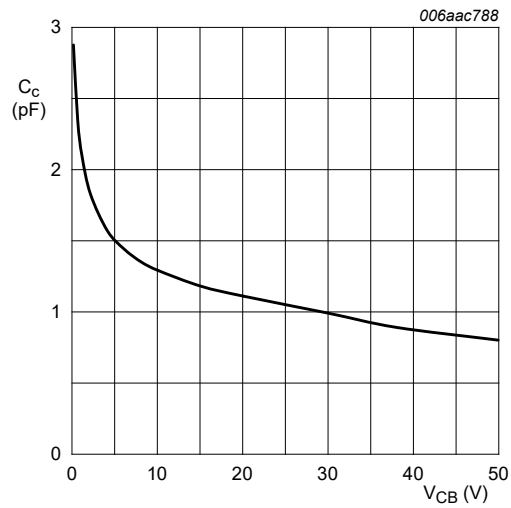
$V_{CE} = 0.3\text{ V}$   
 (1)  $T_{amb} = -40\text{ }^\circ\text{C}$   
 (2)  $T_{amb} = 25\text{ }^\circ\text{C}$   
 (3)  $T_{amb} = 100\text{ }^\circ\text{C}$

**Fig. 6. On-state input voltage as a function of collector current; typical values**



$V_{CE} = 5\text{ V}$   
 (1)  $T_{amb} = -40\text{ }^\circ\text{C}$   
 (2)  $T_{amb} = 25\text{ }^\circ\text{C}$   
 (3)  $T_{amb} = 100\text{ }^\circ\text{C}$

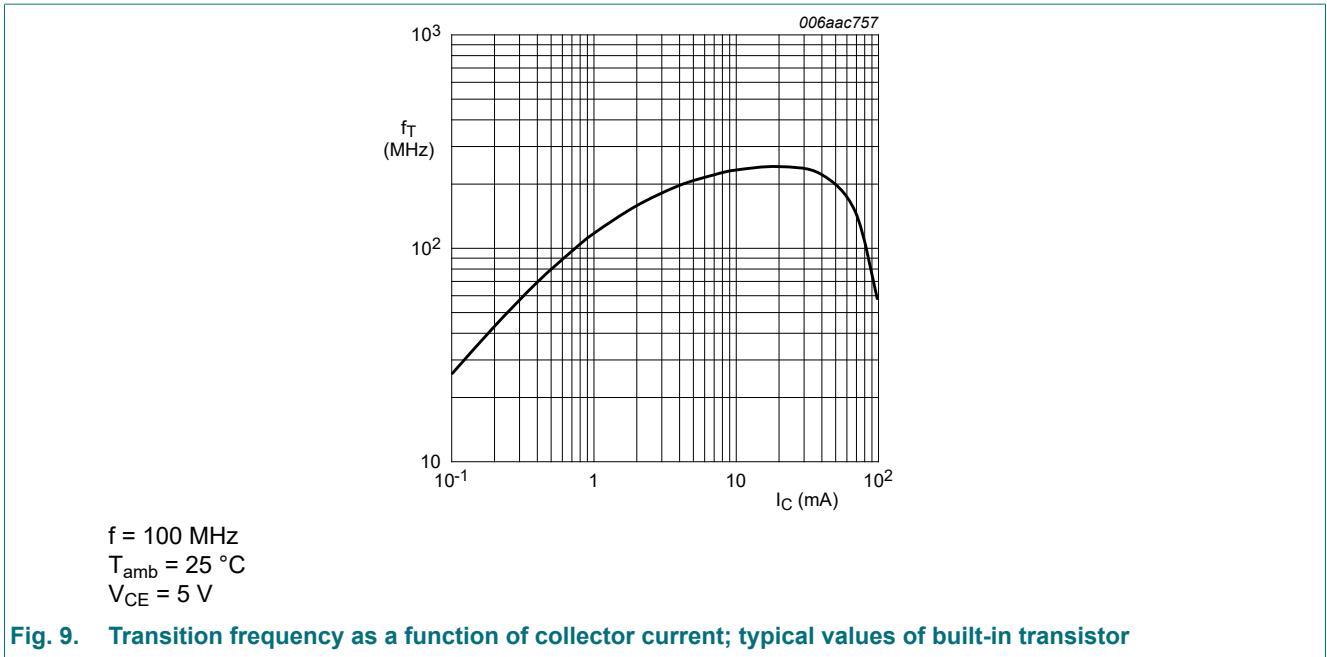
**Fig. 7. Off-state input voltage as a function of collector current; typical values**



$f = 1\text{ MHz}$   
 $T_{amb} = 25\text{ }^\circ\text{C}$

**Fig. 8. Collector capacitance as a function of collector-base voltage; typical values**

50 V, 100 mA NPN/NPN resistor-equipped double transistor; R1 = 10 kΩ, R2 = 47 kΩ



## 11. Test information

### Resistor calculation

- Calculation of bias resistor 1 (R1)

$$R1 = \frac{V(I12) - V(I11)}{I12 - I11}$$

- Calculation of bias resistor ratio (R2/R1)

$$\frac{R2}{R1} = \frac{V(I14) - V(I13)}{R1 \cdot (I14 - I13)} - 1$$

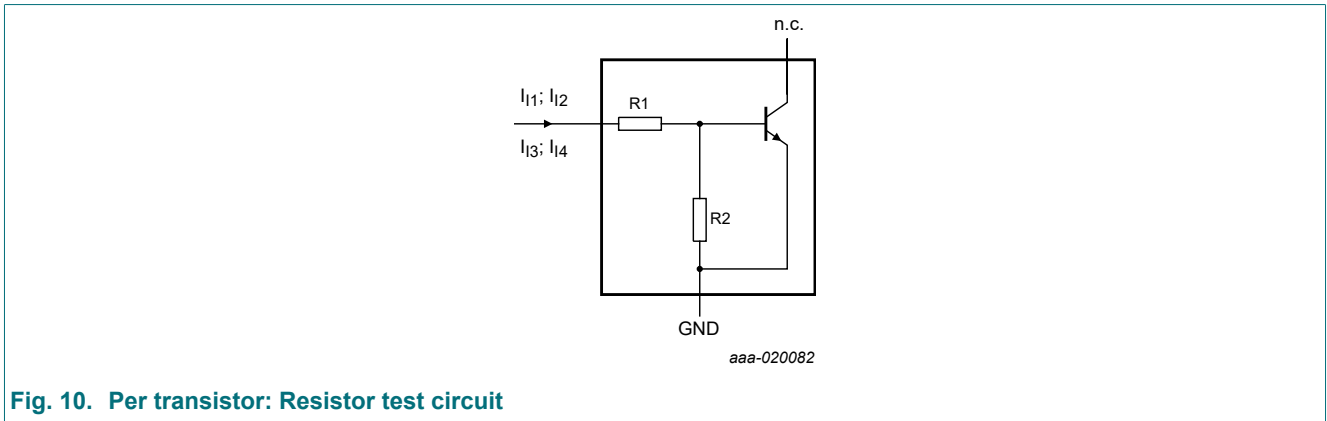


Fig. 10. Per transistor: Resistor test circuit

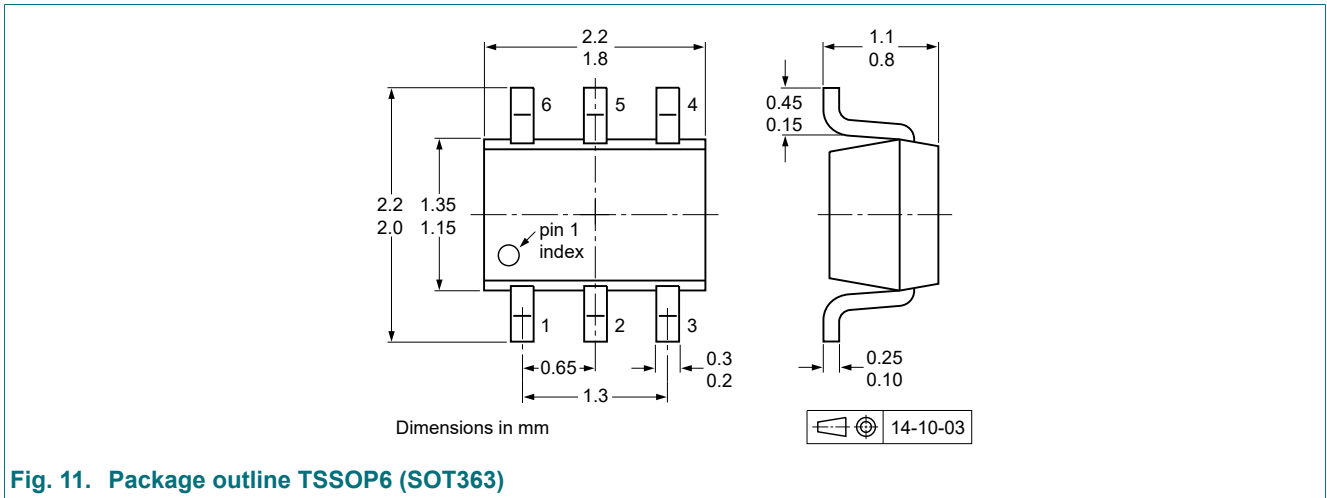
### Resistor test conditions

Table 8. Resistor test conditions

| Type number           | R1 (kΩ) | R2 (kΩ) | Test conditions |                 |                 |                 |
|-----------------------|---------|---------|-----------------|-----------------|-----------------|-----------------|
|                       |         |         | I <sub>I1</sub> | I <sub>I2</sub> | I <sub>I3</sub> | I <sub>I4</sub> |
| <b>Per transistor</b> |         |         |                 |                 |                 |                 |
| PUMH9                 | 10      | 47      | 90 μA           | 140 μA          | -55 μA          | -105 μA         |



## 12. Package outline



### 13. Soldering

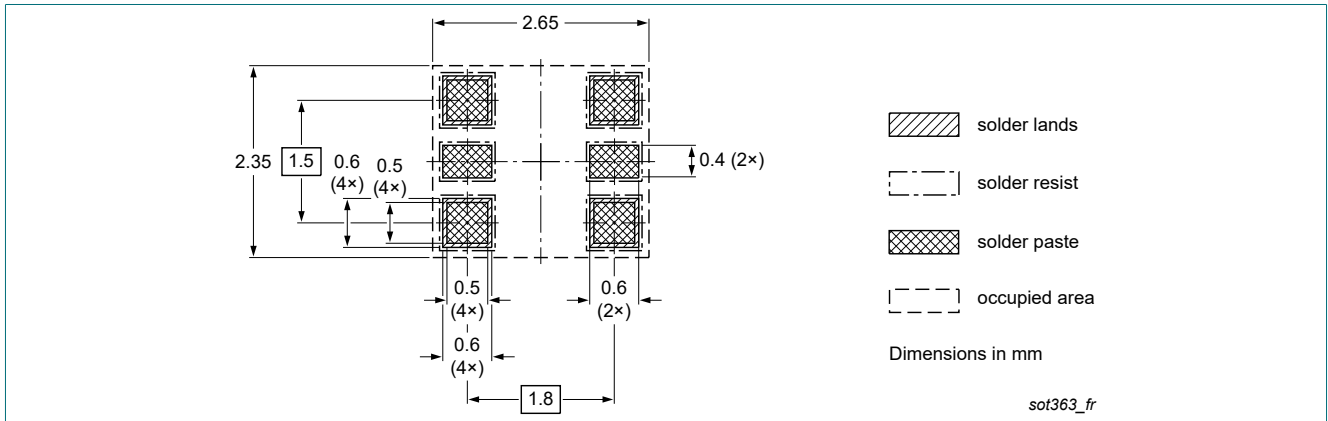


Fig. 12. Reflow soldering footprint for TSSOP6 (SOT363)

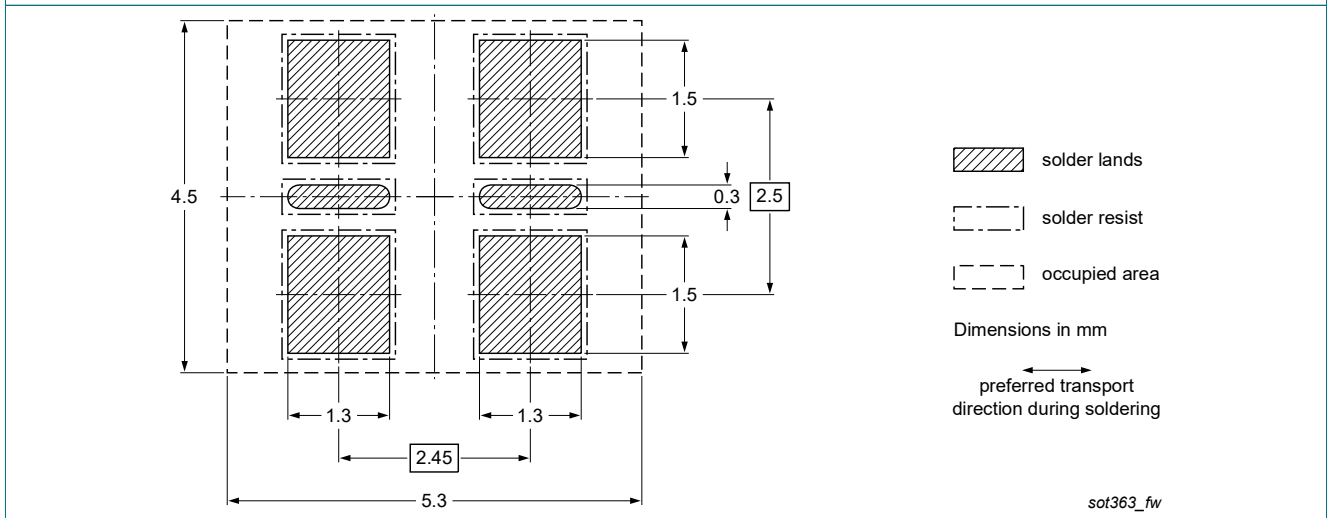


Fig. 13. Wave soldering footprint for TSSOP6 (SOT363)

## 14. Revision history

Table 9. Revision history

| Document ID           | Release date   | Data sheet status     | Change notice | Supersedes            |
|-----------------------|--|-----------------------|---------------|-----------------------|
| PUMH9 v.7             | 20220701   | Product data sheet    | -             | PUMH9 v.6             |
| Modification:         | <ul style="list-style-type: none"> <li>The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia.</li> <li>Legal texts have been adapted to the new company name where appropriate.</li> <li>Family data sheet reduced to single type data sheet.</li> <li>Product changed to non-automotive qualification. Please refer to <a href="http://nexperia.com">nexperia.com</a> for automotive (-Q) product alternative(s).</li> <li>Packing information removed.</li> </ul> |                       |               |                       |
| PUMH9 v.6             | 20190711   | Product data sheet    | -             | PEMH9_PIMH9_PUMH9 v.5 |
| PEMH9_PIMH9_PUMH9 v.5 | 20131112   | Product data sheet    | -             | PIMH9_PUMH9_PEMH9 v.4 |
| PIMH9_PUMH9_PEMH9 v.4 | 20040414   | Product data sheet    | -             | PIMH9_PUMH9_PEMH9 v.3 |
| PIMH9_PUMH9_PEMH9 v.3 | 20030915   | Product specification |               | -                     |

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### Data sheet status

| Document status [1][2]         | Product status [3] | Definition  |
|--------------------------------|--------------------|---|
| Objective [short] data sheet   | Development        | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification      | This document contains data from the preliminary specification.                       |
| Product [short] data sheet     | Production         | This document contains the product specification.                                     |

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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